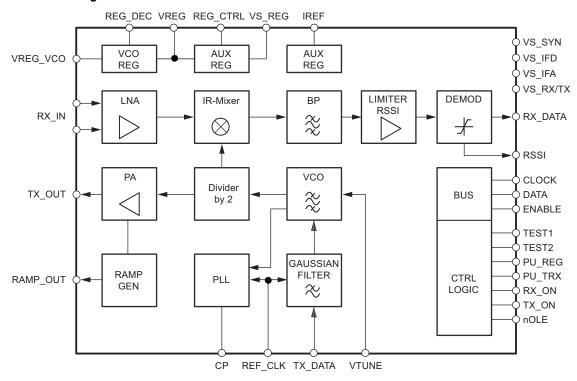
1. Description

The Atmel® ATR2406 is a single chip RF transceiver intended for applications in the 2.4GHz ISM band.

The QFN32-packaged IC is a complete transceiver including image rejection mixer, low IF filter, FM demodulator, RSSI, TX preamplifier, power-ramping generator for external power amplifier, integrated synthesizer, and a fully integrated VCO and TX filter. No mechanical adjustment is necessary in production.

The RF transceiver offers a clock recovery function on-chip.

Figure 1-1. Block Diagram





2. Pin Configuration

Figure 2-1. Pinning QFN32 - 5×5

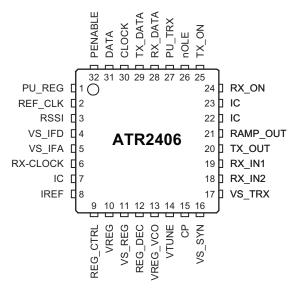


Table 2-1. Pin Description

Pin	Symbol	Function
1	PU_REG	Power-up input for auxiliary regulator
2	REF_CLK	Reference frequency input
3	RSSI	Received signal strength indicator output
4	VS_IFD	Digital supply voltage
5	VS_IFA	Analog supply voltage for IF circuits
6	RX-CLOCK	RX-CLOCK, if RX mode with clock recovery is active
7	IC	Internally connected. Connect to V _S if internal AUX regulator is not used
8	IREF	External resistor for band-gap reference
9	REG_CTRL	Auxiliary voltage regulator control output
10	VREG	Auxiliary voltage regulator output
11	VS_REG	Auxiliary voltage regulator supply voltage
12	REG_DEC	Decoupling pin for VCO_REG
13	VREG_VCO	VCO voltage regulator
14	VTUNE	VCO tuning voltage input
15	CP	Charge-pump output
16	VS_SYN	Synchronous supply voltage
17	VS_TRX	Transmitter receiver supply voltage
18	RX_IN2	Differential receiver input 2
19	RX_IN1	Differential receiver input 1
20	TX_OUT	TX driver amplifier output
21	RAMP_OUT	Ramp generator output for PA power ramping
22	IC	Internally connected, do not connect on PCB
23	IC	Internally connected, do not connect on PCB
24	RX_ON	RX control input



Table 2-1. Pin Description (Continued)

Pin	Symbol	Function						
25	TX_ON	TX control input						
26	NOLE	Open loop enable input						
27	PU_TRX	RX/TX/PLL/VCO power-up input						
28	RX_DATA	ata output						
29	TX_DATA	TX data input						
30	CLOCK	3-wire-bus: Clock input						
31	DATA	3-wire-bus: Data input						
32	ENABLE	3-wire-bus: Enable input						
Paddle	GND	Ground						



3. Functional Description

3.1 Receiver

The RF signal at RF_IN is differentially fed through the LNA to the image rejection mixer IR_MIXER, driving the integrated low-IF band-pass filter. The IF frequency is 864kHz. The limiting IF_AMP with an integrated RSSI function feeds the signal to the digital demodulator DEMOD. No tuning is required. Data slicing is handled internally.

3.2 Clock Recovery

For a 1152Kbit/s data rate, the receiver has a clock recovery function on-chip.

The receiver includes a clock recovery circuit which regenerates the clock out of the received data. The advantage is that this recovered clock is synchronous to the clock of the transmitting device (and thus to the transmitted data), which significantly reduces the load of the processing microcontroller.

The falling edge of the clock is the optimal sampling position for the RX_Data signal, so at this event the data must be sampled by the microcontroller. The recovered clock is available at pin 6.

3.3 Transmitter

The transmit data at TX_DATA is filtered by an integrated Gaussian filter (GF) and fed to the fully integrated VCO operating at twice the output frequency. After modulation, the signal is frequency divided by 2 and fed to the internal preamplifier PA. This preamplifier supplies typically +4dBm output power at TX_OUT.

A ramp-signal generator RAMP_GEN, providing a ramp signal at RAMP_OUT for the external power amplifier, is integrated. The slope of the ramp signal is controlled internally so that spurious requirements are fulfilled.

3.4 Synthesizer

The IR_MIXER, the PA, and the programmable counter (PC) are driven by the fully integrated VCO, using on-chip inductors and varactors. The output signal is frequency divided to supply the desired frequency to the TX_DRIVER, the 0/90 degree phase shifter for the IR_MIXER, and to be used by the PC for the phase detector (PD) (f_{PD} = 1.728MHz). Open loop modulation is supported.

3.5 Power Supply

An integrated band-gap—stabilized voltage regulator for use with an external low-cost PNP transistor is implemented. Multiple power-down and current saving modes are provided.



4. Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameters	Symbol	Min.	Max.	Unit
Supply voltage auxiliary regulator	V_S	-0.3	+4.7	V
Supply voltage	V _S	-0.3	+3.6	V
Control voltages	V _{contr}	-0.3	V _S	V
Storage temperature	T _{stg}	-40	+125	°C
Input RF level	P _{RF}		+10	dBm
ESD protection	V _{ESD_ana}		TBD	V
LOD protection	V_{ESD_dig}		TBD	V

5. Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R_{thJA}	35	K/W

6. Operating Range

Parameters	Symbol	Min.	Max.	Unit
Supply voltage	V_S	2.9	3.6	V
Auxiliary regulator supply voltage	V _{S_BATT}	3.2	4.6	V
Temperature ambient	T _{amb}	-10	+60	°C
Input frequency range	f _{RX}	2400	2483	MHz

7. **Electrical Characteristics**

 V_S = 3.6V with AUX regulator, T_{amb} = 25°C, unless otherwise specified

No.	Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
1	Supply						
1.1	Supply voltage	With AUX regulator	V _S	3.2	3.6	4.6	V
1.2	Supply voltage	Without AUX regulator	V _S	2.9	3.0	3.6	V
4.0	DV averally average	CW mode (peak current)	I _S		57		mA
1.3	RX supply current	Burst mode at 10Kbits/s ⁽⁴⁾	I _S		625		μA
4.4	TVt	CW mode (peak current)	I _S		42		mA
1.4	TX supply current	Burst mode at 10Kbits/s ⁽⁴⁾	I _S		500		μA
1.5	Battery lifetime of a remote control application using an AVR®	See Section 11. "Appendix: Current Calculations for a Remote Control" on page 21					
1.6	Supply current in power-down mode	With AUX regulator PU_TRX = 0; PU_REG = 0	I _S		< 1		μA
1.7	Supply current in power-down mode	Without AUX regulator PU_TRX = 0; PU_REG = 0	I _S		< 1		μA
2	Voltage Regulator						
2.1	AUX regulator		VREG		3.0		V
2.2	VCO regulator		VREG_VCO		2.7		V
3	Transmitter Part						
3.1	TX data rate			72/14	kBits/s		
3.2	Output power		PTX		4		dBm
3.3	TX data filter clock	9 taps in filter	f _{TXFCLK}	10.368/13.824			MHz
3.4	Frequency deviation	To be tuned by GFCS bits	GF _{FM_nom}		±400		kHz
3.5	Frequency deviation scaling ⁽³⁾	GFFM = $GF_{FM_nom} \times GFCS$ (Refer to bus protocol D9 to D11)	GFCS	60		130	%
3.6	Frequency drift	With standard loop filter and slot length of 1400µs (refer to the application note "ATR2406 Loop Filter and Data Rates")	Dfo (drift)			±40	kHz
3.7	Harmonics	$BW = 100kHz^{(1)}$				-41.2	dBm
3.8	Spurious emissions 30 to 1000MHz 1 to 12.75GHz 1.8 to 1.9GHz 5.15 to 5.3GHz	BW = 100kHz ⁽¹⁾				-57 -57 -57 -57	dBm dBm dBm dBm
4	Ramp Generator, Pin 21						
4.1	Minimum output voltage	TX_ON = low	V_{min}		0.7		V
4.2	Maximum output voltage	Refer to bus protocol D12 to D13	V_{max}	1.1		1.9	V
4.3	Rise time		t _r		5		μs

- Notes: 1. Measured and guaranteed only on the Atmel® evaluation board, including microstrip filter, balun, and smart radio frequency (smart RF) firmware. Conducted measured.
 - 2. Timing is determined by external loop filter characteristics. Faster timing can be achieved by modification of the loop filter. For further information refer to the application notes.
 - 3. The Gaussian filter control setting (GFCS) is used to compensate production tolerances by tuning the modulation deviation in production to the nominal value of 400kHz.
 - 4. Burst mode with 0.9% duty cycle



7. Electrical Characteristics (Continued)

 V_S = 3.6V with AUX regulator, T_{amb} = 25°C, unless otherwise specified

No.	Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
4.4	Fall time		t _f		5		μs
5	Receiver Part						
5.1	RX input impedance	Differential	Z _{in}		170 + j0		Ω
5.2	Sensitivity	At input for BER $\leq 10^{-3}$ at 1152Kbits/s ⁽¹⁾			-93		dBm
5.3	Third order input intercept point		IIP3		-15		dBm
5.4	Intermodulation rejection	BER < 10 ⁻³ , wanted at –83dBm, level of interferers in channels N + 2 and N + 4 ⁽¹⁾	IM ₃	32			dBc
5.5	Co-channel rejection	BER < 10 ⁻³ , wanted at –76dBm ⁽¹⁾	R _{CO}	-11			dBc
5.6	Adjacent channel rejection ±1.728MHz	BER < 10 ⁻³ , wanted at –76dBm, adjacent level referred to wanted channel level ⁽¹⁾	R _{i (N - 1)}	14			dBc
5.7	Bi-adjacent channel rejection ±3.456MHz	BER < 10 ⁻³ , wanted at –76dBm, bi-adjacent level referred to wanted channel level ⁽¹⁾	R _{i (N - 2)}	30			dBc
5.8	Rejection with ≥ 3 channels separation ≥ ±5.128MHz	BER < 10^{-3} , wanted at -76 dBm, n ≥ 3 adjacent level referred to wanted channel level ⁽¹⁾	R _{i (n} ≥ ₃₎	40			dBc
5.9	Out of band rejection > 6MHz	BER < 10^{-3} , wanted at -83 dBm at 2.45 GHz ⁽¹⁾	Bl _{df>6MHz}	38			dBc
5.10	Out of band rejection 2300MHz to 2394MHz 2506MHz to 2600GHz	BER < 10 ⁻³ , wanted at –83dBm at 2.45GHz ⁽¹⁾	Bl _{near}	47			dBc
5.11	Out of band rejection 30MHz to 2300MHz 2600MHz to 6GHz	BER < 10 ⁻³ , wanted at –83dBm at 2.45GHz ⁽¹⁾	Bl _{far}	57			dBc
6	RSSI Part						
6.1	Maximum RSSI output voltage	Under high RX input signal level	$V_{RSSImax}$		2.1		V
6.2	RSSI output voltage, monotonic over range –96dBm to –36dBm	With –33dBm at RF input With –96dBm at RF input	V_{RSSI}		1.9 0.1		V V
7	VCO						
7.1	Oscillator frequency defined at TX output	Over full temperature range ⁽¹⁾		2400		2483	MHz
7.2	Frequency control voltage range		V _{VTUNE}	0.5		V _{CC} – 0.5	V
7.3	VCO tuning input gain defined at TX output		G _{VCO}		240		MHz/V

Notes:

- 1. Measured and guaranteed only on the Atmel[®] evaluation board, including microstrip filter, balun, and smart radio frequency (smart RF) firmware. Conducted measured.
- 2. Timing is determined by external loop filter characteristics. Faster timing can be achieved by modification of the loop filter. For further information refer to the application notes.
- 3. The Gaussian filter control setting (GFCS) is used to compensate production tolerances by tuning the modulation deviation in production to the nominal value of 400kHz.
- 4. Burst mode with 0.9% duty cycle



7. Electrical Characteristics (Continued)

 V_S = 3.6V with AUX regulator, T_{amb} = 25°C, unless otherwise specified

No.	Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit			
8	Synthesizer									
8.1	External reference input frequency	D7 = 0 D7 = 1	REF_CLK		10.368 13.824		MHz MHz			
8.2	Sinusoidal input signal level (peak-to-peak value)	AC-coupled sine wave	REF_CLK	500		1000	mV_PP			
8.3	Scaling factor prescaler		S _{PSC}		32/33		-			
8.4	Scaling factor main counter		S _{MC}	8	6/87/88/89)	-			
8.5	Scaling factor swallow counter		S _{SC}	0		31	-			
9	Phase Detector									
9.1	Phase detector comparison frequency		f _{PD}		1728		kHz			
10	Charge-pump Output									
10.1	Charge-pump output current	$V_{CP} = 1/2 V_{CC}$	I _{CP}		±2		mA			
10.2	Leakage current	$V_{CP} = 1/2 V_{CC}$	Ι _L		±100	1000	pA			
11	Timing Conditions ⁽¹⁾⁽²⁾									
11.1	Transmit to receive time	Reference clock stable	$TX \to RX time$		200		μs			
11.2	Receive to transmit time	Reference clock stable	$RX \to TX \text{ time}$		200		μs			
11.3	Channel switch time	Reference clock stable	CS time		200		μs			
11.4	Power down to transmit	Reference clock stable	$PD \to TR \ time$		250		μs			
11.5	Power down to receive	Reference clock stable	$PD \to RX time$		200		μs			
11.6	Programming register	Reference clock stable	PRR time		3		μs			
11.7	PLL settling time	Reference clock stable	PLL set time		200		μs			
12	Interface Logic Input and Output	Signal Levels, Pin DATA, CLOCK,	ENABLE							
12.1	HIGH-level input voltage	Logic 1	V _{IH}	1.4		3.1	V			
12.2	LOW-level input voltage	Logic 0	V _{IL}	-0.3		+0.4	V			
12.3	HIGH-level output voltage	Logic 1	V _{OH}			3.1	V			
12.4	LOW-level output voltage	Logic 0	V _{OL}	0			V			
12.5	Input bias current	Logic 1 or logic 0	I _{bias}	- 5		+5	μA			
12.6	3-wire bus clock frequency	only on the Atmel® evaluation board	f _{CLKmax}			10	MHz			

Notes: 1. Measured and guaranteed only on the Atmel[®] evaluation board, including microstrip filter, balun, and smart radio frequency (smart RF) firmware. Conducted measured.

- 2. Timing is determined by external loop filter characteristics. Faster timing can be achieved by modification of the loop filter. For further information refer to the application notes.
- 3. The Gaussian filter control setting (GFCS) is used to compensate production tolerances by tuning the modulation deviation in production to the nominal value of 400kHz.
- 4. Burst mode with 0.9% duty cycle



8. PLL Principle

Figure 8-1. PLL Principle

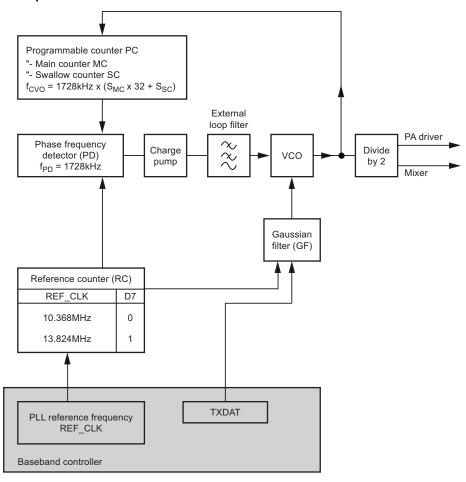


Table 8-1 shows the LO frequencies for RX and TX in the 2.4-GHz ISM band. There are 95 channels available. Since the ATR2406 supports wideband modulation with 400-kHz deviation, every second channel can be used without overlap in the spectrum.

Table 8-1. LO Frequencies

Mode	f _{IF} /kHz	Channel	f _{ANT} /MHz	f _{vco} /MHz divided by 2	S _{MC}	S _{sc}	N
		C0	2401.056	2401.056	86	27	2779
		C1	2401.920	2401.920	86	28	2780
TX							
		C93	2481.408	2481.408	89	24	2872
		C94	2482.272	2482.272	89	25	2873
		C0	2401.056	2401.920	86	28	2780
		C1	2401.920	2402.784	86	29	2781
RX	864						
		C93	2481.408	2482.272	89	25	2873
		C94	2482.272	2483.136	89	26	2874

8.1 TX Register Setting

The following 16-bit word has to be programmed for TX.

MSB	MSB											LSB			
Data bits															
D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	1	P	A	GFCS		1	RC	M	С	SC					

Note:

D12 and D13 are only relevant if ramping generator in conjunction with external PA is used, otherwise it can be programmed 0 or 1.

Table 8-2. Output Power Settings with Bits D12 - D13

	PA (Output Power Settings)											
D13	D12	RAMP_OUT (Pin 21)										
0	0	1.3V										
0	1	1.35V										
1	0	1.4V										
1	1	1.75V										

The VRAMP voltage is used to control the output power of an external power amplifier. The voltage ramp is started with the TX_ON signal.

These bits are only relevant in TX mode.

8.2 RX Register Setting

There are two RX settings possible. For a data rate of 1152kBits/s, an internal clock recovery function is implemented.

8.3 Register Setting Without Clock Recovery

Must be used for data rates below 1.152Mbits/s.

MSB	MSB												LSB		
	Data bits														
D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	1	Х	Х	Х	Х	Х	0	RC	М	С	SC				

Note:

X values are not relevant and can be set to 0 or 1.



8.4 RX Register Setting with Internal Clock Recovery

Recommended for 1.152Mbit/s data rate.

The output pin of the recovered clock is pin 6. The falling edge of the recovered clock signal samples the data signal.

MSB												
	Data bits											
D24	D23	D22	D21	D20	D19	D18	D17	D16				
1	0	1	0	0	0	0	0	0				

															LSB
							ata bits								
D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
0	0	Х	Х	Х	Х	Х	0	RC	М	С			SC		

Note:

X values are not relevant and can be set to 0 or 1.

8.5 PLL Settings

RC, MC and SC bits control the synthesizer frequency as shown in Table 8-3, Table 8-4 on page 12 and Table 8-5 on page 13.

Formula for calculating the frequency:

TX frequency: f_{ANT} = 864kHz × (32 × S_{MC} + S_{SC}) RX frequency: f_{ANT} = 864kHz × (32 × S_{MC} + S_{SC} – 1)

Table 8-3. PLL Settings of the Reference Counter Bit D7

RC (Reference Counter)					
D7	CLK Reference				
0	10.368MHz				
1	13.824MHz				

Table 8-4. PLL Settings of the Main Counter Bits D5 to D6

MC (Main Counter)					
D6	D5	S _{MC}			
0	0	86			
0	1	87			
1	0	88			
1	1	89			

Table 8-5. PLL Settings of the Swallow Counter Bits D0 to D4

	SC (Swallow Counter)					
D4	D3	D2	D1	D0	S _{sc}	
0	0	0	0	0	0	
0	0	0	0	1	1	
0	0	0	1	0	2	
1	1	1	0	1	29	
1	1	1	1	0	30	
1	1	1	1	1	31	

8.6 GFCS Adjustment

The Gaussian filter control setting (GFCS) is used to compensate for production tolerances by tuning the modulation deviation in production to the nominal value of 400kHz. These bits are only relevant in TX mode.

Table 8-6. GFCS Adjustment of Bits D9 - D11

	GFCS					
D11	D10	D9	GFCS			
0	0	0	60%			
0	0	1	70%			
0	1	0	80%			
0	1	1	90%			
1	0	0	100%			
1	0	1	110%			
1	1	0	120%			
1	1	1	130%			

8.7 Control Signals

The various transceiver functions are activated by the following control signals. A timing proposal is shown in Figure 8-3 on page 15.

Table 8-7. Control Signals and Functions

Signal	Functions
PU_REG	Activates AUX voltage regulator and the VCO voltage regulator supplying the complete transceiver
PU_TRX	Activates RX/TX blocks
RX_ON	Activates RX circuits: DEMOD, IF AMP, IR MIXER
TX_ON	Activates TX circuits: PA, RAMP GEN, Starts RAMP SIGNAL at RAMP_OUT
NOLE	Disables open loop mode of the PLL



8.8 Serial Programming Bus

The transceiver is programmed by the SPI (CLOCK, DATA and ENABLE).

After setting the enable signal to low, the data is transferred bit by bit into the shift register on the rising edge of the clock signal, starting with the MSBit. When the enable signal has returned to high, the programmed information is active. Additional leading bits are ignored and there is no check made of how many clock pulses arrived during enable low.

The programming of the transceiver is done by a 16-bit or 25-bit data word (for the RX clock recovery mode).

8.9 3-wire Bus Timing

Figure 8-2. 3-wire Bus Protocol Timing Diagram

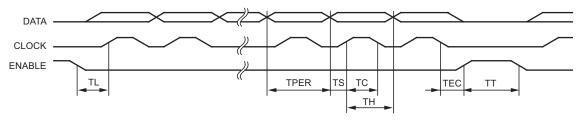


Table 8-8. 3-wire Bus Protocol Table

Description	Symbol	Minimum Value	Unit
Clock period	TPER	100	ns
Set time data to clock	TS	20	ns
Hold time data to clock	TH	20	ns
Clock pulse width	TC	60	ns
Set time enable to clock	TL	100	ns
Hold time enable to data	TEC	0	ns
Time between two protocols	TT	250	ns

Figure 8-3. Example TX and RX Timing Diagram

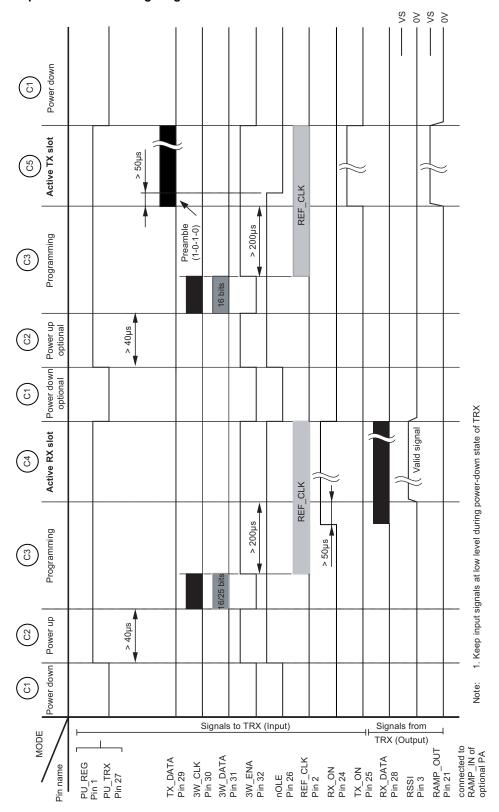




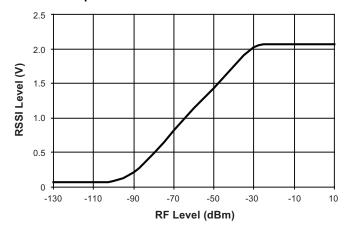
Table 8-9. Description of the Conditions/States

Condition	Description
C1	Power down ATR2406 is switched off and the supply current is lower than 1µA.
C2	Power up ATR2406 is powered up by toggling PU_REG and PU_TRX to high. PU_REG enables the external AUX regulator transistor including VCO regulator. PU_TRX enables internal blocks like the PLL and the VCO. Depending on the value of the external capacitors (for example, at the AUX regulator, if one is used), it is necessary to wait at least 40µs until the different supply voltages have settled.
C3	Programming The internal register of the ATR2406 is programmed via the three-wire interface. At TX, this is just the PLL (transmit channel) and the deviation (Gaussian filter). At RX, this is just the PLL (receive channel) and, if the clock recovery is used, also the bits to enable this option. At the start of the three-wire programming, the enable signal is toggled from high to low to enable clocking the data into the internal register. When the enable signal rises again to high, the programmed data is latched. This is the time point at which the settling of the PLL starts. It is necessary to wait the settling time of 200µs so that the VCO frequency is stable. The reference clock needs to be applied to ATR2406 for at least the time when the PLL is in operation, which is the programming state (C3) and the active slot (C4, C5). Out of the reference clock, several internal signals are also derived, for example, the Gaussian filter circuitry and TX_DATA sampling.
C4	This is the receive slot where the transmit burst is received and data as well as recovered clock are available.
C5	This is the active transmit slot. As soon as TX_DATA is applied to ATR2406, the signal nOLE toggles to low which enables modulation in open-loop mode. The preamble (1-0-1-0 pattern) should start being sent at the start of TX_ON.

8.10 Received Signal Strength Indication (RSSI)

The RSSI is given as an analog voltage at the RSSI pin. A typical plot of the RSSI value is shown in Figure 8-4.

Figure 8-4. Typical RSSI Value versus Input Power



9. Application Circuit

The Atmel® ATR2406 requires only a few low-cost external components for operation. A typical application is shown in Figure 9-3 on page 18.

9.1 Typical Application Circuit

Figure 9-1. Microcontroller Interfacing with General Purpose MCU, Pin Connections between Microcontroller and ATR2406

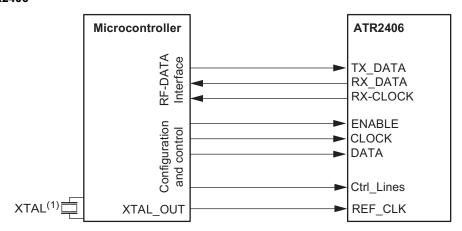
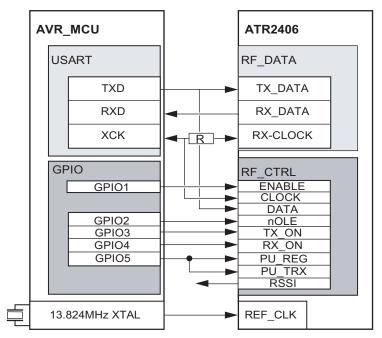


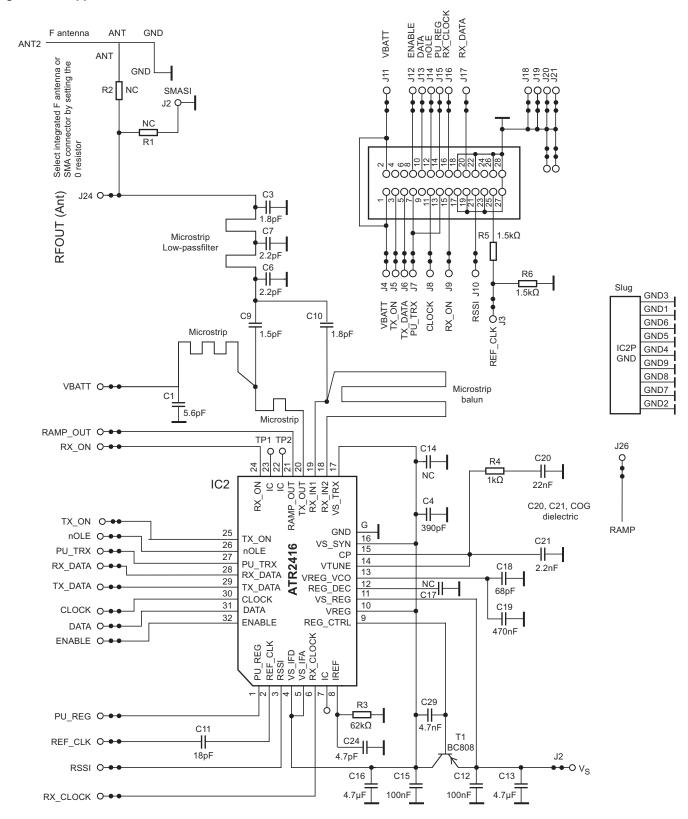
Figure 9-2. Example with AVR MCU



Note: 1. XTAL: for example, XRFBCC-NANL; 13.824MHz, 10ppm Order at: Taitien Electronic, Taitien Specific No.: A009-x-B26-3, SMD



Figure 9-3. Application Circuit for ATR2406-DEV-BOARD





10. PCB Layout Design

Figure 10-1. PCB Layout ATR2406-DEV-BOARD

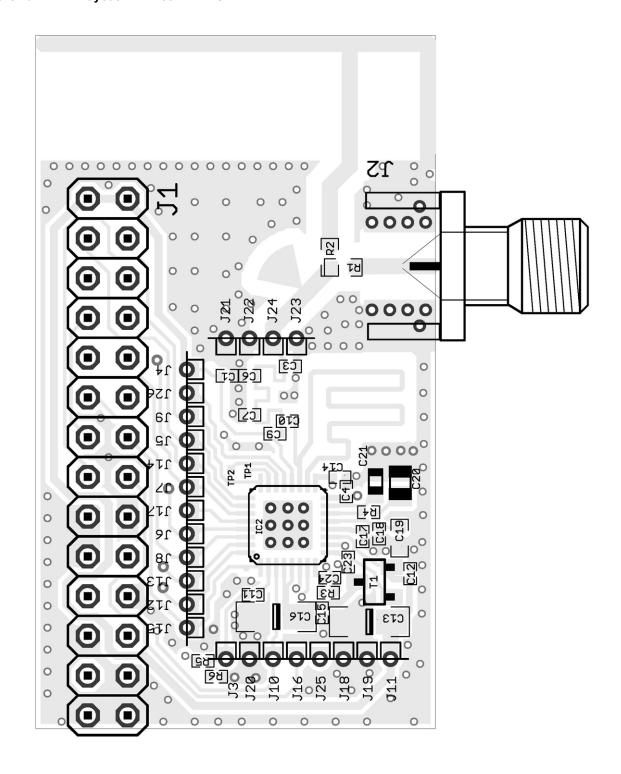




Table 10-1. Bill of Materials

Part	Value	Part Number	Vendor	Package	Comment	
C1	5.6pF			0402		
C3, C10	1.8pF			0402		
C4	390pF			0402		
C5	4.7pF			0402	NC	
C6, C7	2.2pF			0402		
C9	1.5pF			0402		
C11	18pF			0402		
C12, C15	100nF			0402		
C13, C16	4.7µF	B45196H2475M109	Epcos [®]	3216	Optional ⁽²⁾	
C14	1nF			0402	NC	
C17	3.3nF			0402	NC	
C18	68pF			0402		
C19	470nF			0402/0603		
C20	22nF, COG	GRM21B5C1H223JA01	Murata	0805	COG, important for good RF performance	
C21	2.2nF, COG	GRM1885C1H222JA01	Murata	0603	COG, important for good RF performance	
C23	4.7nF			0402		
C24	4.7pF			0402		
R3	62kΩ	62k, ≤ 5%		0402		
R4	1.0kΩ	1k0, ≤ 5%		0402		
R5	1.5kΩ	1k5, ≤ 5%		0402	Ref_Clk level, optional ⁽¹⁾	
R6	1.5kΩ	1k5, ≤ 5%		0402	Ref_Clk level, optional ⁽¹⁾	
IC2	ATR2406	ATR2406	Atmel	MLF32		
T1	BC808-40	BC808-40, any standard type can be used, but it is important that be "-40"!	Vishay [®] , Philips [®] , etc.	SOT-23	Optional ⁽²⁾	
MSUB	MSUB FR4 FR4, e_r = 4.4 at 2.45GHz, H = 500μ m, T = 35μ m, t _{and} = 0.02, surface, that is, chem. tin or chem. gold					

Notes: 1. Not necessary if supplied RefClk level is within specification range

Table 10-2. Parts Count Bill of Materials

Parts Count	Required (Minimal BOM)	Optional (Depending on Application)
Capacitors 0402	14	14
Capacitors >0402	2	4
Resistors 0402	2	2
Inductors 0402	-	-
Semiconductors	1	2

^{2.} If no AUX regulator is used, then T1 and C16 can be removed and a jumper is needed from the collector to the emitter pad. Additionally, pin 7 of the ATR2406 has to be connected to pin 4 or pin 5 to use the integrated F antenna, set jumper R2 (0R resistor 0603)

11. Appendix: Current Calculations for a Remote Control

Assumptions:

, 100 a.m.p.1101101	
Protocol	A data packet consists of 24 bytes. 24 bytes = 240bits (USART connection) T _{packet_length} = 210µs at 1.152Mbits/s
Channel	The system will use five predefined channels for frequency hopping spread spectrum (FHSS) which gives improved immunity against interferers
Loop filter	Loop filter settling time will be 110µs
Handheld device	If not in use, the handheld device will be in power-down mode with the AVR® watchdog timer disabled. The AVR power-down current is typically 1.25µA. If an external voltage regulator is used, additional power-down current has to be taken into account
Base station device	The base station will periodically scan all the channels of the used subset. The base station will stay on one channel for 2 seconds. If the base station receives a correct packet, an acknowledge will be returned to the handheld device. The power consumption of the base station device is not power-sensitive, as this part of the application is normally mains powered

Basic Numbers:

Peak current ATR2406 in TX at 1.152Kbits/s	42mA
Peak current ATR2406 in RX at 1.152Kbits/s	57mA
Peak current ATR2406 with synthesizer running	26mA
Current ATmega88 active	5mA
Current ATmega88 power down (no WDT)	1.25µA
Current ATmega88 power down (+ WDT)	5µA
Loop settling time of ATR2406	110µs
Configuration of ATR2406	30µs
Time needed for exchanging a packet at 1.152Kbits/s	210µs

Amount of Current Needed to Transmit One Packet:

Amount of Guitent Needed to Transmit One Lacket.		
Q1 = $(0.005A + 0.026A) \times 5030 \mu s$ = $155 \mu As$ (charge up time ATR2406 + AVR internal calculations)		
Q2 = $(0.005A + 0.026A) \times 30\mu s = 0.93\mu As$ (charge for configuring the ATR2406)		
Q3 = $(0.005A + 0.026A) \times 110 \mu s$ = $3.41 \mu As$ (charge for settling the loop filter)		
Q4 = $(0.005A + 0.042A) \times 210 \mu s$ = $9.87 \mu As$ (charge for transmitting the packet)		
Q5 = (0.005A) ΄ 250 μs = 1.25μAs (charge for turn around (TX to RX, RX to TX, etc.))		
Q6 = $(0.005A + 0.026A) \times 30\mu s = 0.93\mu As$ (charge for configuring the ATR2406)		
Q7 = $(0.005A + 0.026A) \times 60\mu s$ = 1.86 μ As (charge for settling the loop filter)		
Q8 = $(0.005A + 0.057A) \times 50\mu s = 3.10 \mu As$ (charge until valid data can be received)		
Q9 = $(0.005A + 0.057A) \times 210\mu s$ = $13.02\mu As$ (charge for receiving the packet)		
Q10 = $(0.005A + 0.057A) \times 50\mu s = 3.1\mu As$ (charge for latency before receiving)		



A successful packet exchange needs the following charge $Q = Q1 + Q2 + Q3 + Q4 + Q5 + Q6 + Q7 + Q8 + Q9 + Q10 = 192.47 \mu As$

As the described system is a FHSS system with 5 different channels, the system has to do this up to five times before the packet is acknowledged by the base station. The average will be 2.5 times. In the case of an interfered environment, some more retries may be required; therefore, it is assumed the factor will be 3. The power-up time is included only once, as the cycle will be completed without powering up and down the handheld in order to be as power efficient as possible.

Average current needed for a packet exchange:

 $155\mu As + (37.5\mu As \times 3) = 267.5\mu As$

If the device will be used 1000 times a day \rightarrow 3.1 μ A

Average current in active mode:

→ System power down current:

Current ATmega88: $1.25\mu A$ Current ATR2406: $1.0\mu A$ Current VREG (+ ShutDown): $2.75\mu A$

Assumed average power-down current is 5µA.

→ Overall power consumption is 8.1µA

It is assumed the system uses a small battery with a capacity of 100mAh. This is 100.000μAh.

→ Battery lifetime will be around: 12345 hours = 514 days = 1.4 years.

The most important factor is to get the power-down current as low as possible!

Example:

Assume a system where the handheld is used just 10 times per day.

 \rightarrow I_{active} = 0.031µA

and assuming the power-down current of this device is just 4 µA.

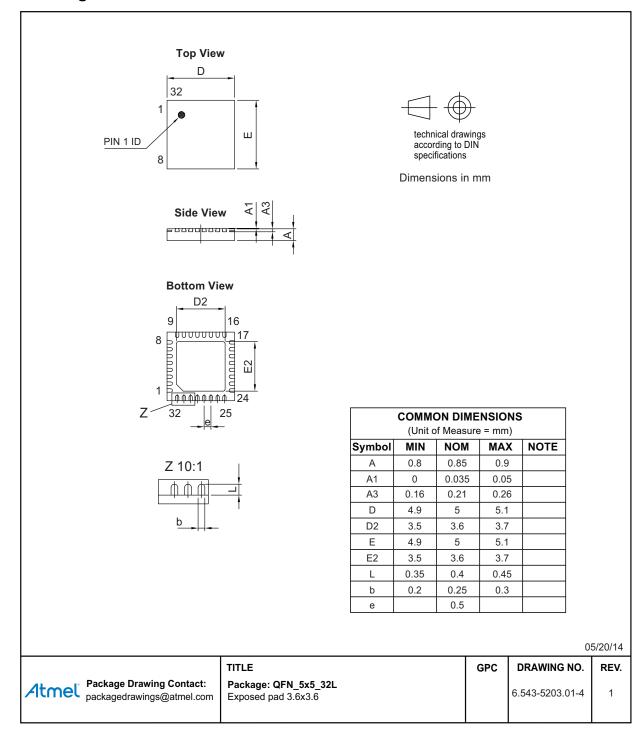
- \rightarrow I = 0.031 μ A + 4 μ A = 4.03 μ A
- → Battery lifetime will be around 24807 hours = 1033 days = 2.83 years.
- → Power-down current is the main factor influencing the battery lifetime.



12. Ordering Information

Extended Type Number	Package	Remarks	MOQ
ATR2406-PNQW	QFN32 - 5x5	Taped and reeled, Pb-free	6000

13. Package Information





14. Recommended Footprint/Landing Pattern

Figure 14-1. Recommenced Footprint/Landing Pattern

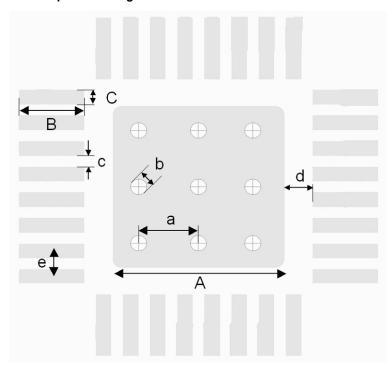


Table 14-1. Recommended Footprint/Landing Pattern Signs

Sign	Size
А	3.2mm
В	1.2mm
С	0.3mm
a	1.1mm
b	0.3mm
С	0.2mm
d	0.55mm
e	0.5mm



15. Revision History

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.

Revision No.	History
4779Q-ISM-09/14	Section 11 "Ordering Information" on page 23 updated
	Section 12 "Package Information" on page 23 updated
4779P-ISM-09/14	Section 11 "Ordering Information" on page 23 updated
4779O-ISM-03/14	Put datasheet in the latest template
4779N-ISM-12/08	Put datasheet in the latest template
	Section 12 "Package Information" on page 22 updated
4779M-ISM-02/07	Put datasheet in the latest template
	Table 9-1 "Bill of Materials" on page 19 updated
4779L-ISM-08/06	Table "Electrical Characteristics" on pages 6 to 8 updated
	• Section 10 "Appendix: Current calculations for a remote control" on pages 20 to 21 updated
	Table "Ordering Information" on page 22 updated
	Minor corrections to grammar and style throughout document
4779K-ISM-06/06	Put datasheet in a new template
	Table "Electrical Characteristics" on pages 6 to 8 updated
	Section 10 "Appendix: Current calculations for a remote control" on pages 20 to 21 added
	Ordering information on page 22 updated





authorized, or warranted for use as components in applications intended to support or sustain life.

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